

International IOR Rectifier

30ETH06SPbF 30ETH06-1PbF

Hyperfast Rectifier

Features

- Hyperfast Recovery Time
- Low Forward Voltage Drop
- Low Leakage Current
- 125°C Operating Junction Temperature
- Dual Diode Center Tap
- Lead-Free ("PbF" suffix)

$t_{rr} = 28\text{ns typ.}$
 $I_{F(AV)} = 30\text{Amp}$
 $V_R = 600\text{V}$

Description/ Applications

State of the art Hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, Hyperfast recover time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.


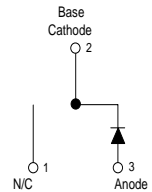

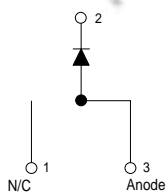
These devices are intended for use in PFC Boost stage in the AC-DC section of SMPS, inverters or as freewheeling diodes.

The IR extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

Absolute Maximum Ratings

Parameters	Max	Units
V_{RRM} Peak Repetitive Reverse Voltage	600	V
$I_{F(AV)}$ Average Rectifier Forward Current @ $T_C = 103^\circ\text{C}$	30	A
I_{FSM} Non Repetitive Peak Surge Current @ $T_J = 25^\circ\text{C}$	200	
T_J Operating Junction Temperature	- 65 to 125	$^\circ\text{C}$
T_{STG} Operating Storage Temperature	- 65 to 150	

Case Styles

<p>30ETH06SPbF</p>  <div style="text-align: center;">  <p>D²PAK</p> </div>	<p>30ETH06-1PbF</p>  <div style="text-align: center;">  <p>TO-262</p> </div>
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Electrical Characteristics @ T_J = 25°C (unless otherwise specified)

Parameters	Min	Typ	Max	Units	Test Conditions
V _{BR} , V _F Breakdown Voltage, Blocking Voltage	600	-	-	V	I _R = 100μA
V _F Forward Voltage	-	2.0	2.6	V	I _F = 30A, T _J = 25°C
	-	1.34	1.75	V	I _F = 30A, T _J = 150°C
I _R Reverse Leakage Current	-	0.3	50	μA	V _R = V _R Rated
	-	60	500	μA	T _J = 150°C, V _R = V _R Rated
C _T Junction Capacitance	-	33	-	pF	V _R = 600V
L _S Series Inductance	-	8.0	-	nH	Measured lead to lead 5mm from package body

Dynamic Recovery Characteristics @ T_J = 25°C (unless otherwise specified)

Parameters	Min	Typ	Max	Units	Test Conditions
t _{rr} Reverse Recovery Time	-	28	35	ns	I _F = 1.0A, di _F /dt = 50A/μs, V _R = 30V
	-	31	-		T _J = 25°C
	-	77	-		T _J = 125°C
I _{RRM} Peak Recovery Current	-	3.5	-	A	T _J = 25°C
	-	7.7	-		T _J = 125°C
Q _{rr} Reverse Recovery Charge	-	65	-	nC	T _J = 25°C
	-	345	-		T _J = 125°C

I_F = 30A
V_R = 200V
di_F/dt = 200A/μs

Thermal - Mechanical Characteristics

Parameters	Min	Typ	Max	Units
T _J Max. Junction Temperature Range	- 65	-	125	°C
T _{Stg} Max. Storage Temperature Range	- 65	-	150	
R _{thJC} Thermal Resistance, Junction to Case	-	0.7	1.1	°C/W
R _{thJA} ① Thermal Resistance, Junction to Ambient	-	-	70	
R _{thCS} ② Thermal Resistance, Case to Heatsink	-	0.2	-	
Weight	-	2.0	-	g
	-	0.07	-	(oz)
Mounting Torque	6.0	-	12	Kg-cm
	5.0	-	10	lbf.in
Marking Device	30ETH06S		Case style D ² Pak	
	30ETH06-1		Case style TO-262	

① Typical Socket Mount

② Mounting Surface, Flat, Smooth and Greased

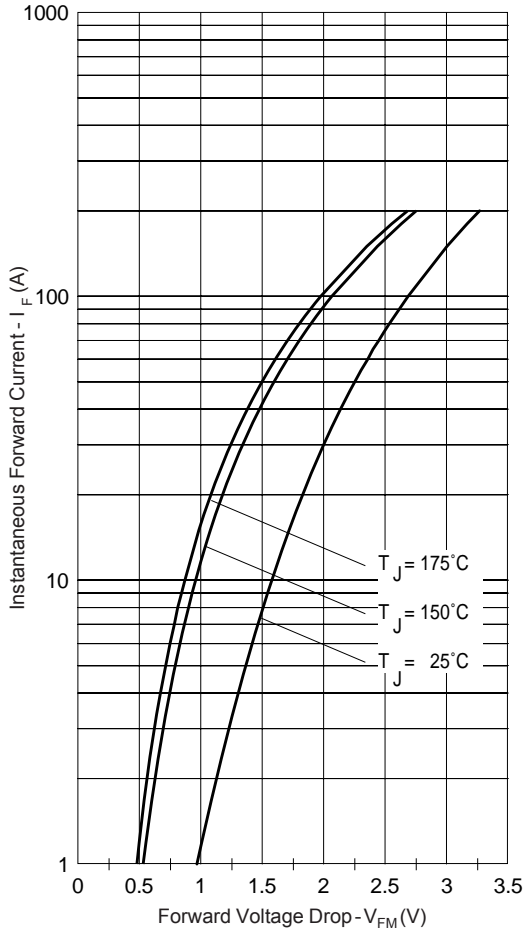


Fig. 1 - Typical Forward Voltage Drop Characteristics

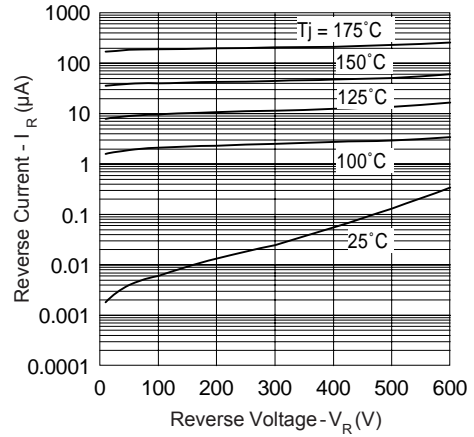


Fig. 2 - Typical Values Of Reverse Current Vs. Reverse Voltage

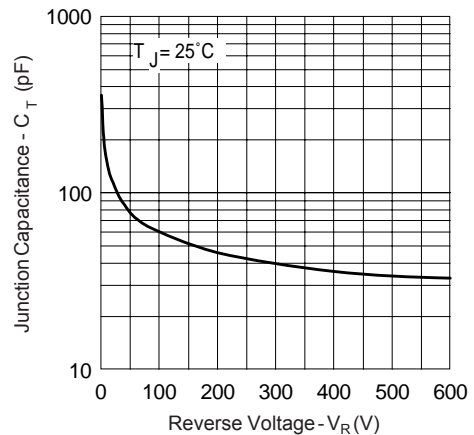


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

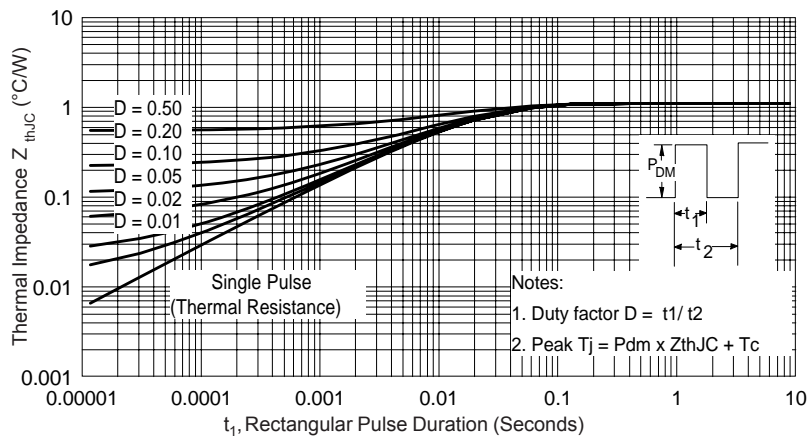


Fig. 4 - Max. Thermal Impedance Z_{thJC} Characteristics

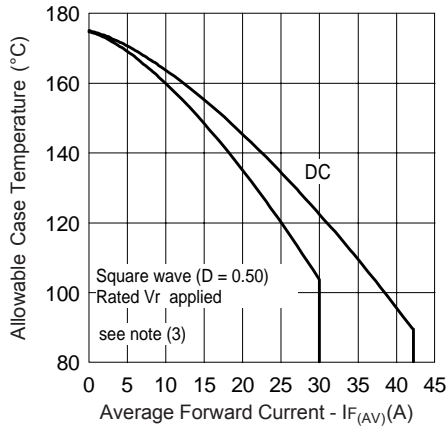


Fig. 5 - Max. Allowable Case Temperature Vs. Average Forward Current

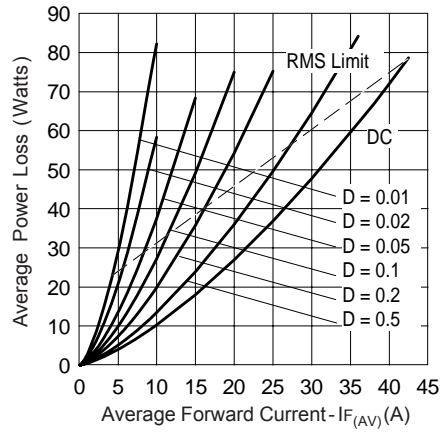


Fig. 6 - Forward Power Loss Characteristics

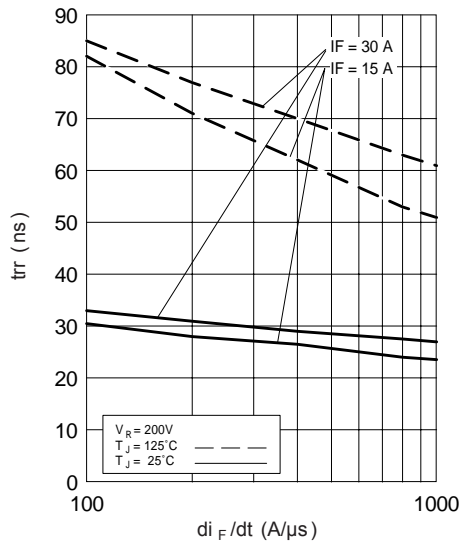


Fig. 7 - Typical Reverse Recovery vs. di_F/dt

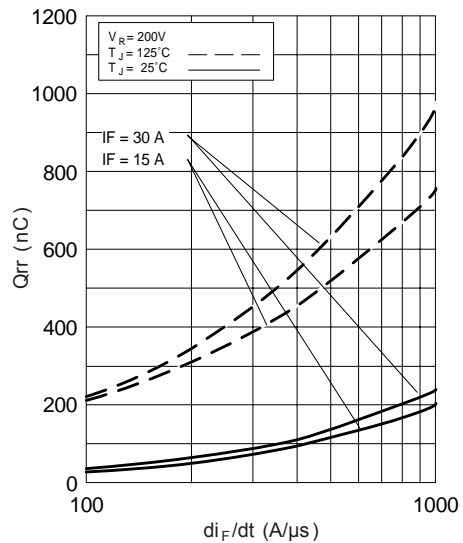


Fig. 8 - Typical Stored Charge vs. di_F/dt

- (3) Formula used: $T_C = T_J - (P_d + P_{d_{REV}}) \times R_{thJC}$;
 $P_d = \text{Forward Power Loss} = I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$ (see Fig. 6);
 $P_{d_{REV}} = \text{Inverse Power Loss} = V_{R1} \times I_R (1 - D)$; $I_R @ V_{R1} = \text{rated } V_R$

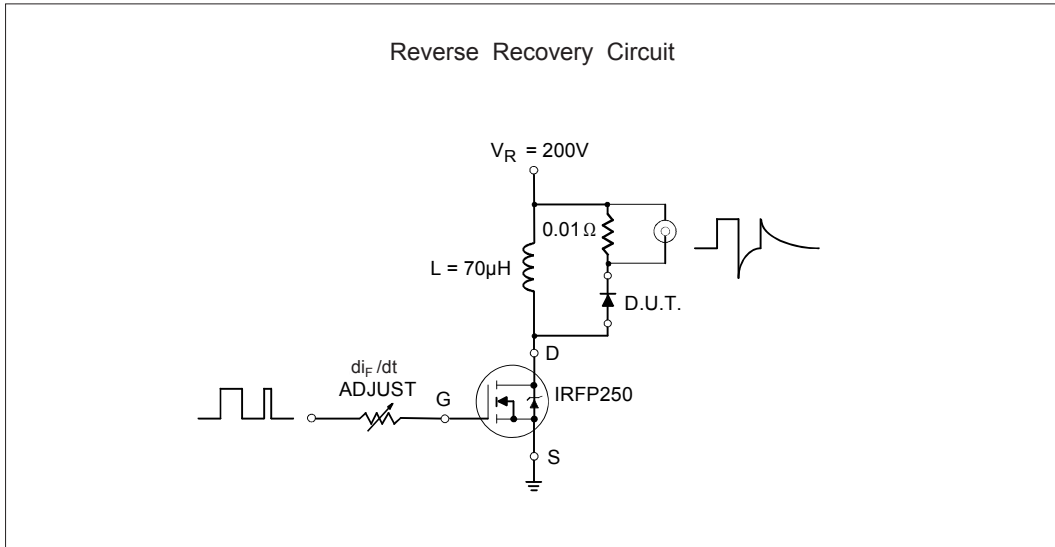


Fig. 9- Reverse Recovery Parameter Test Circuit

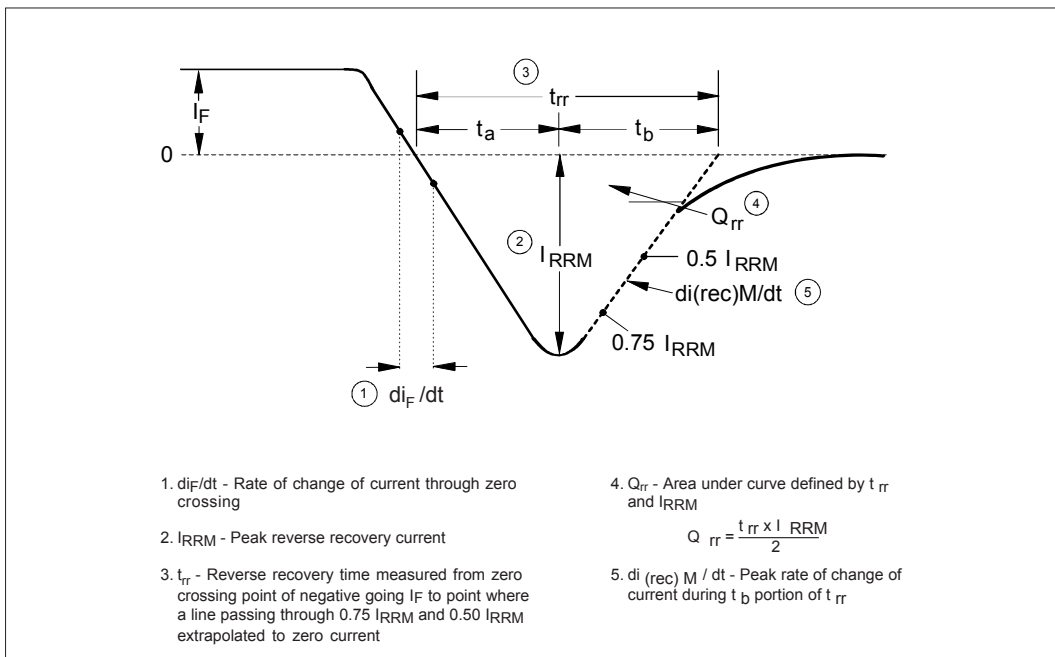


Fig. 10 - Reverse Recovery Waveform and Definitions

Outline Table

NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994
2. DIMENSIONS ARE SHOWN IN MILLIMETERS [INCHES]
3. DIMENSION D & E DO NOT INCLUDE MOLD FLASH. MOLD FLASH SHALL NOT EXCEED 0.127 [.005"] PER SIDE. THESE DIMENSIONS ARE MEASURED AT THE OUTMOST EXTREMES OF THE PLASTIC BODY.
4. DIMENSION b1 AND c1 APPLY TO BASE METAL ONLY.
5. CONTROLLING DIMENSION: INCH.

SYMBOL	DIMENSIONS		DIMENSIONS		NOTES
	MILLIMETERS		MILLIMETERS	INCHES	
A	4.06	4.83	.160	.190	4
A1	0.90	0.254	.000	.010	
b	0.51	0.99	.020	.039	
b1	0.51	0.89	.020	.035	
b2	1.14	1.78	.045	.070	4
c	0.38	0.74	.015	.029	
c1	0.38	0.58	.015	.023	4
c2	1.14	1.65	.045	.065	
D	8.51	9.65	.335	.380	3
D1	6.86	-	.270	-	
E	9.65	10.67	.380	.420	3
E1	6.22	-	.245	-	
e	2.54	BSC	.100	BSC	3
H	14.61	15.88	.575	.625	
L	1.78	2.79	.070	.110	4
L1	-	1.65	.065	-	
L2	1.27	1.78	.050	.070	4
L3	0.25	BSC	.010	BSC	
L4	4.78	5.28	.188	.208	4
m	17.78	-	.700	-	
m1	8.89	-	.350	-	4
n	11.43	-	.450	-	
o	2.08	-	.082	-	4
p	3.81	-	.150	-	
R	0.51	0.71	.020	.028	4
θ	90°	93°	90°	93°	

LEAD ASSIGNMENTS

HEXFET

- 1.- GATE
- 2, 4.- DRAIN
- 3.- SOURCE

IGBTs, CoPACK

- 1.- GATE
- 2, 4.- COLLECTOR
- 3.- EMITTER

DIODES

- 1.- ANODE *
- 2, 4.- CATHODE
- 3.- ANODE

* PART DEPENDENT.

Conform to JEDEC outline D²Pak (SMD-220)
Dimensions in millimeters and (inches)

NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994
2. DIMENSIONS ARE SHOWN IN MILLIMETERS [INCHES]
3. DIMENSION D & E DO NOT INCLUDE MOLD FLASH. MOLD FLASH SHALL NOT EXCEED 0.127 [.005"] PER SIDE. THESE DIMENSIONS ARE MEASURED AT THE OUTMOST EXTREMES OF THE PLASTIC BODY.
4. THERMAL PAD CONTOUR OPTIONAL WITHIN DIMENSION E, L1, D1 & E1.
5. DIMENSION b1 AND c1 APPLY TO BASE METAL ONLY.
6. CONTROLLING DIMENSION: INCH.
- 7.- OUTLINE CONFORM TO JEDEC TO-262 EXCEPT A1(max), b(min.) AND D1(min.) WHERE DIMENSIONS DERIVED THE ACTUAL PACKAGE OUTLINE.

SYMBOL	DIMENSIONS		DIMENSIONS		NOTES
	MILLIMETERS		MILLIMETERS	INCHES	
A	4.06	4.83	.160	.190	5
A1	2.03	3.02	.080	.119	
b	0.51	0.99	.020	.039	
b1	0.51	0.89	.020	.035	
b2	1.14	1.78	.045	.070	5
b3	1.14	1.73	.045	.068	
c	0.38	0.74	.015	.029	5
c1	0.38	0.58	.015	.023	
c2	1.14	1.65	.045	.065	4
D	8.38	9.65	.330	.380	
D1	6.86	-	.270	-	3, 4
E	9.65	10.67	.380	.420	
E1	6.22	-	.245	-	4
e	2.54	BSC	.100	BSC	
L	13.46	14.10	.530	.555	4
L1	-	1.65	.065	-	
L2	3.56	3.71	.140	.146	4
L3	-	-	-	-	

LEAD ASSIGNMENTS

HEXFET

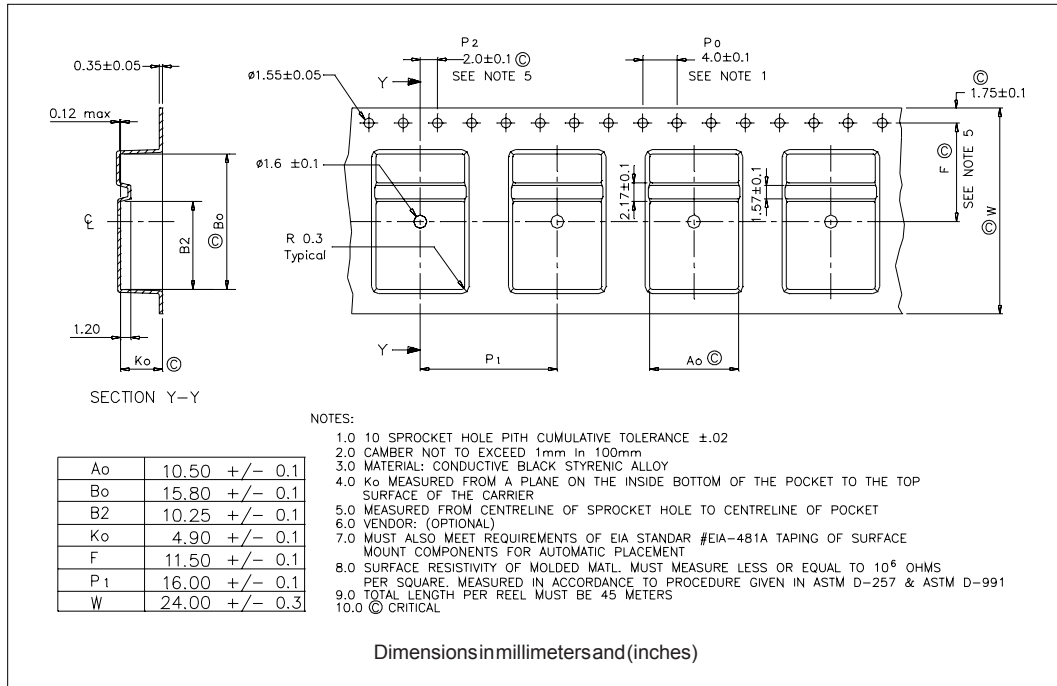
- 1.- GATE
- 2.- DRAIN
- 3.- SOURCE
- 4.- DRAIN

IGBTs, CoPACK

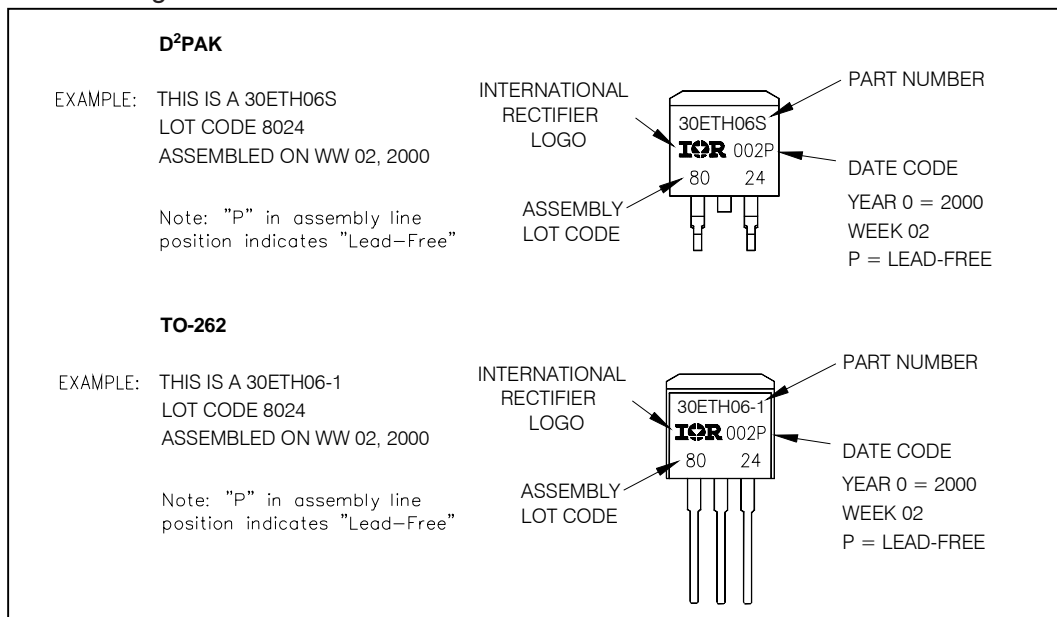
- 1.- GATE
- 2.- COLLECTOR
- 3.- EMITTER
- 4.- COLLECTOR

Modified JEDEC outline TO-262
Dimensions in millimeters and (inches)

Tape & Reel Information



Part Marking Information



Ordering Information Table

Device Code									
	<table border="1" style="margin: auto;"> <tr> <td style="padding: 5px;">30</td> <td style="padding: 5px;">E</td> <td style="padding: 5px;">T</td> <td style="padding: 5px;">H</td> <td style="padding: 5px;">06</td> <td style="padding: 5px;">S</td> <td style="padding: 5px;">TRL</td> <td style="padding: 5px;">PbF</td> </tr> </table>	30	E	T	H	06	S	TRL	PbF
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	<table style="margin: auto;"> <tr> <td style="text-align: center;">①</td> <td style="text-align: center;">②</td> <td style="text-align: center;">③</td> <td style="text-align: center;">④</td> <td style="text-align: center;">⑤</td> <td style="text-align: center;">⑥</td> <td style="text-align: center;">⑦</td> <td style="text-align: center;">⑧</td> </tr> </table>	①	②	③	④	⑤	⑥	⑦	⑧
①	②	③	④	⑤	⑥	⑦	⑧		
1	- Current Rating (30 = 30A)								
2	- E = Single Diode								
3	- T = TO-220, D ² Pak								
4	- H = HyperFast Recovery								
5	- Voltage Rating (06 = 600V)								
6	- • S = D ² Pak • -1 = TO-262								
7	- • none = Tube (50 pieces) • TRL = Tape & Reel (Left Oriented, for D ² PAK package) • TRR = Tape & Reel (Right Oriented, for D ² PAK package)								
8	- • none = Standard Production • PbF = Lead-Free								

Data and specifications subject to change without notice.
This product has been designed and qualified for Industrial Level and Lead-Free.
Qualification Standards can be found on IR's Web site.